AD179A Datasheet

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AD179A Features

CPU

- 32bit DSP
- Maximum speed 160MHz
- Interrupts with 8 priority level

Memory

Optional built-in flash memory

Clocks

- On-chip 16 MHz clock
- On-chip 200KHz lower-temperature-drift clock

Audio APA

- Support for driving 4 or 8 ohm speaker
- Mono Class-D Speaker Amplifier
 - 0.42W/8 Ω @3.7V
 - $0.17W/8 \Omega @2.4V$
 - 0.62W/4 Ω @3.7V
 - 0.25W/4 Ω @2.4V

Peripherals

- Three multi-function 16-bit timers, support capture and PWM mode
- Two UART Controllers(UART0/1) supports DMA and Flow Control
- One IIC Master controller
- Two SPI Master / Slaver controller with DMA

SPI0 support 4bit, SPI1 support 2bit

- 16-channel 10-bit general purpose ADC
- 4-channel Advance PWM controller
- 17 Individually programmable and multiplexed GPIO pins
- Digital peripheral crossbar
- Support Touch Key of pulse counter
- Up to 8 external interrupt / wake-up source (low power available,can be multiplexed to any I/O)
- Watchdog

PMU

- Less than 2uA soft off current
- **VBAT** range : 2.0V to 5.5V
- HPVDD range: 2.0V to 5.5V
- IOVDD range: 2.0V to 3.4V

Packages

QFN20(3mm*3mm)

Temperature

- Operating temperature: -40° C to $+85^{\circ}$ C
- Storage temperature: -65°C to +150°C

Applications

- Sound Toy
- Audio player
- Universal Microcontroller



1 Block Diagram

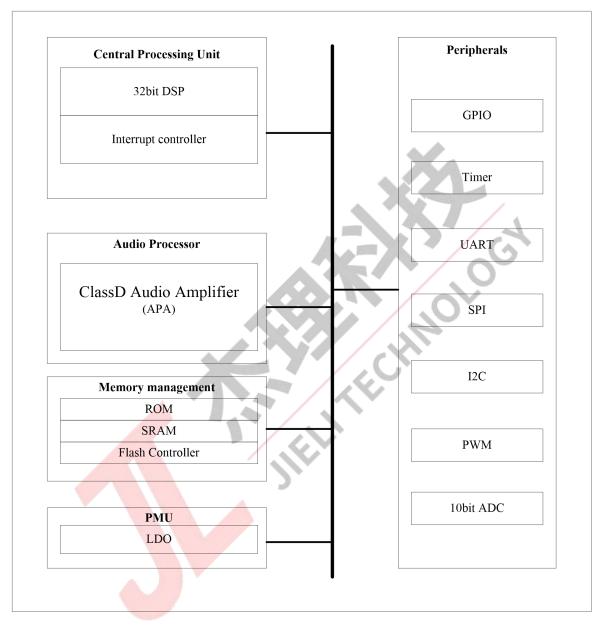


Figure 1-1 AD179A Block Diagram



2 Pin Definition

2.1 Pin Assignment

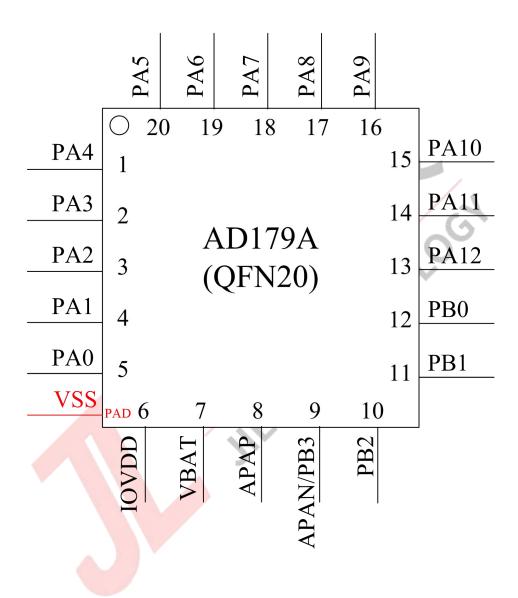


Figure 2-1 AD179A Package Diagram



2.2 Pin Description

Table 2-1 AD179A Pin Description

PIN NO.	Name	Туре	Function	Other Function
1	PA4	I/O	GPIO	ADC4:ADC Input Channel 4; PWMCK0;
2	PA3	I/O	GPIO	ADC3:ADC Input Channel 3; CAP0:Timer0 Capture; PWM0:Timer0 PWM Output;
3	PA2	I/O	GPIO	ADC2:ADC Input Channel 2; TMR0:Timer0 Clock Input;
4	PA1	I/O	GPIO	ADC1:ADC Input Channel 1; LVD:Low Voltage Detect;
5	PA0	I/O	GPIO (pull up)	Long press reset; ADC0:ADC Input Channel 0;
6	IOVDD	РО	Power supply for GPIO	Built-in linear voltage regulator output;
7	VBAT	PI		Power supply input;
8	APAP	О		Class-D APA Positive Output;
0	APAN	О		Class-D APA Negative Output;
9	PB3	I/O	5V tolerant IO	/*/.(;
10	PB2	I/O	5V tolerant IO (pull up)	MCLR:Low level reset;
11	PB1	I/O	5V tolerant IO	Serial port code upgrade pin;
12	PB0	I/O	5V tolerant IO	
13	PA12	I/O	GPIO	ADC12:ADC Input Channel 12;
14	PA11	I/O	GPIO	ADC11:ADC Input Channel 11;
15	PA10	I/O	GPIO	ADC10:ADC Input Channel 10;
16	PA9	I/O	GPIO (pull down)	ADC9:ADC Input Channel 9;
17	PA8	I/O	GPIO (pull down)	ADC8:ADC Input Channel 8;
18	PA7	I/O	GPIO (pull down)	ADC7:ADC Input Channel 7;
19	PA6	I/O	GPIO (pull down)	ADC6:ADC Input Channel 6;
20	PA5	I/O	GPIO	ADC5:ADC Input Channel 5; PWMCK1;
PAD	VSS	G		System ground;

Pin Type	Description	Pin Type	Description
P	Power	I/O	Input or Output
PI	Power Input	I	Input
PO	Power Output	О	Output
AO	Analog Output	G	Ground



CROSSBAR								
SPI0	SPI1	IIC	UART0	UART1	PWMCH0	PWMCH1		
SPI0_CLK	SPI1_CLK	IIC_CLK	UART0_TX	UART1_TX	PWMCH0L	PWMCH1L		
SPI0_DI	SPI1_DI	IIC_DAT	UART0_RX	UART1_RX	PWMCH0H	PWMCH1H		
SP0_D0	SPI1_D0							
SP0_DAT2								
SP0_DAT3								

	Input Channel x6		Output Channel x8			
WAKEUP	Timer1	IRFLT	PWM1	CLK_OUT0	APA_DOP	
PWMFP0	Timer2	TOUCH_CAP	PWM2	CLK_OUT1	APA_DON	
PWMFP1	CAP1	UART1_CTS	UART1_RTS	CLK_OUT2		
EXT_CLK	CAP2				A	



3 Electrical Characteristics

3.1 Absolute Maximum Ratings

Table 3-1

Symbol	Parameter	Min	Max	Unit
Topt	Operating temperature	-40	+85	°C
Tstg	Storage temperature	-65	+150	°C
VBAT	Supply Voltage	-0.3	6	V
$V_{\rm IOVDD}$	Voltage applied at IOVDD	-0.3	3.6	V
$ m V_{GPIO}$	Voltage applied to GPIO	-0.3	IOVDD+0.3	V
$V_{ m HVIO}$	Voltage applied to High Voltage Resistant IO	-0.3	+5.5	V

Note: The chip can be damaged by any stress in excess of the absolute maximum ratings listed below

3.2 ESD Protectio

Table 3-2

Parameter	Тур.	Test pin	Reference standard
Human Body Mode	±4KV	All pins	JEDEC EIA/JESD22-A114
Machine Mode	±200V	All pins	JEDEC EIA/JESD22-A115
Charge Device Model	±2KV	All pins	JEDEC EIA/JESD22-C101F
I otolo vie	±200mA	All GPIO pins	JEDEC STANDARD NO.78E
Latch up	1.5xVopmax	All power pins	JEDEC STANDARD NO./8E

Note: 1.5 xVopmax = 1.5 times maximum operating voltage.

3.3 PMU Characteristics

Table 3-3

Symbol	Parameter Parameter	Min	Тур	Max	Unit	Test Conditions
VBAT	Voltage Input	2.0	3.7	5.5	V	_
IONDD	Voltage output	2.0	3.0	3.4	V	VBAT = 4.2V, 10mA loading
10 V D D	IOVDD Loading current		-	100	mA	IOVDD=3.3V@VBAT ≥ 3.6V
V_{LVD}	Voltage input	1.8	2.5	2.5	V	Low-Voltage Detection of IOVDD



3.4 IO Input/Output Electrical Logical Characteristics

Table 3-4

GPIO input ch	GPIO input characteristics								
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions			
$V_{\rm IL}$	Low-Level Input Voltage	-0.3	_	0.3* IOVDD	V	IOVDD = 3.0V			
$ m V_{IH}$	High-Level Input Voltage	0.7* IOVDD	_	IOVDD+0.3	V	IOVDD = 3.0V			
High Voltage R	esistant IO input chara	ecteristics							
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions			
V _{IL}	Low-Level Input Voltage	-0.3	_	0.3* IOVDD	V	IOVDD = 3.0V			
$ m V_{IH}$	High-Level Input Voltage 0.7* IOVDD		_	+5V	V	IOVDD = 3.0V			
Resistant IO o	atput characteristics								
Symbol	Paramete	er	GPIO	Тур	Unit	Test Conditions			
	0.1*IOVDD Driv	PA0~PA12	HD=1:-7 HD=2:-22 HD=3:-27		IOVDD = 3.0V				
$ m V_{OL}$			PB0~PB3	-7	mA				
	0.1*HPVDD Driv APA IO total current l	APAN APAP	-400	S.	VBAT=3.7V				
$ m V_{OH}$	0.9*IOVDD Driv	PA0~PA12	HD=1 :7 HD=2 : 24 HD=3 : 56	mA	IOVDD = 3.0V				
· OII		T Y	PB0~PB3	7	11111				
	0.9*HPVDD Driv APA IO total current l	APAN APAP	400		VBAT=3.7V				

3.5 Internal Resistor Characteristics

Table 3-5

Port	Internal Pull-Up Resistor	Internal Pull-Down Resistor	Comment
PA0~PA12,PB0~PB3 10K		200K	 PA0,PB2 default pull up PA6~PA9 default pull down Internal pull-up/pull-down resistance accuracy ±20%



3.6 Audio APA Characteristics

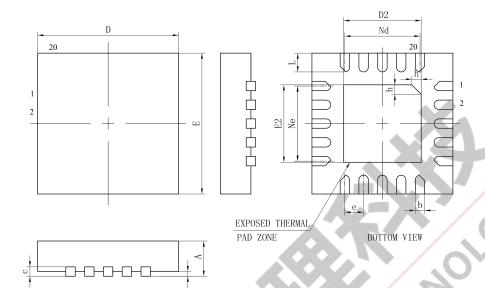
Table 3-6

_			Table 3-6			_	~
Parameter	MODE				Conditions		
Frequency Response		20	_	20K	Hz	R _L =10K	,VBAT=3.7V
		_	1.57	_	Vrms	$R_L=4\Omega$	
	Diff (N to P)	_	1.83	_	Vrms	$R_L=8\Omega$	f=1kHz/0dB
		_	2.22	_	Vrms	R _L =10K	VBAT=3.7V
Output Swing	Single-ended	_	1.11	_	Vrms	R _L =10K	
o usp ut o ming		_	0.99	_	Vrms	$R_L=4\Omega$	
	Diff (N to P)	_	1.17		Vrms	$R_L=8\Omega$	f=1kHz/0dB
		_	1.44		Vrms	R _L =10K	VBAT=2.4V
	Single-ended	_	0.72		Vrms	R _L =10K	
		_	0.62		W	$R_L=4\Omega$	f=1kHz/0dB
Output power	Diff (N to P)	_	0.42	<u></u> 4	W	$R_L=8\Omega$	VBAT=3.7V
output power		_	0.25		W	$R_L=4\Omega$	f=1kHz/0dB
		_	0.17	/ /_ \	W	$R_L=8\Omega$	VBAT=2.4V
		_	-31	-	dB	$R_L=4\Omega$	f=1kHz/0dB
	Diff (N to P)	_	-35		dB	$R_L=8\Omega$	A-Weighted
		_	-75	_	dB	R _L =10K	VBAT=3.7V
THD+N	Single-ended	10-11	-70	/-X	dB	R _L =10K	VBIII 3.7 V
THE		7-8	-31	V	dB	$R_L=4\Omega$	f=1kHz/0dB A-Weighted
	Diff (N to P)		-36		dB	$R_L=8\Omega$	
		4	-73	_	dB	R _L =10K	VBAT=2.4V
	Single-ended	_	-70	_	dB	R _L =10K	VBM1 2.4V
	1	_	97	_	dB	$R_L=4\Omega$	f=1kHz/0dB
	Diff (N to P)	_	97	_	dB	$R_L=8\Omega$	A-Weighted
			95	_	dB	R _L =10K	VBAT=3.7V
S/N	Single-ended		75	_	dB	R _L =10K	VBM1 3.7V
5/14		_	94	_	dB	$R_L=4\Omega$	f=1kHz/0dB
	Diff (N to P)		94	_	dB	$R_L=8\Omega$	A-Weighted
	A	_	88	_	dB	R _L =10K	VBAT=2.4V
	Single-ended	_	72	_	dB	R _L =10K	V DA1-2.4 V
		_	88	_	dB	$R_L=4\Omega$	—————————————————————————————————————
	Diff (N to P)	_	88	_	dB	$R_L=8\Omega$	f=1kHz/-60dB A-Weighted
		_	86	_	dB	R _L =10K	VBAT=3.7V
Dynamic Range	Single-ended	_	75		dB	R _L =10K	V DA1-3./V
Dynamic Kange		_	87	_	dB	$R_L=4\Omega$	£11.11. / 60 1B
	Diff (N to P)	_	87	_	dB	$R_L=8\Omega$	f=1kHz/-60dB
		_	85	_	dB	R _L =10K	A-Weighted
	Single-ended	_	74	_	dB	R _L =10K	VBAT=2.4V



4 Package Information

4.1 QFN20_3×3mm

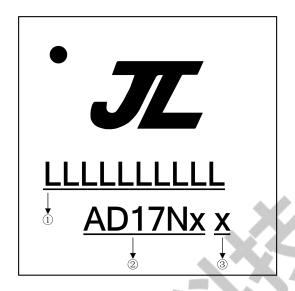


SYMBOL.	MILLIMETER					
SIMBUL	MIN	NOM	MAX			
A	0.70	0.75	0.80			
A1	_	0.02	0.05			
ь	0.15	0. 20	0. 25			
с	0. 18	0.20	0. 25			
D	2. 90	3.00	3. 10			
D2	1. 55	1.65	1.75			
e	0. 40BSC					
Ne		1. 60BSC				
Nd	1. 60BSC					
Е	2. 90	3.00	3. 10			
E2	1.55	1.65	1.75			
L	0.35	0.40	0.45			
h	0. 20	0.25	0.30			
L/F载体尺寸 (Mi1)	75*75					

Figure 4-1 AD179A Package



5 IC Marking Information



- ① LLLLLLLLL: Production Batch
- ② AD17Nx: Chip Model
- 3 Built-in flash size
 - 0: No Flash Memory
 - 2: 2Mbit Flash
 - 4: 4Mbit Flash
 - 8: 8Mbit Flash
 - 6: 16Mbit Flash
 - 3: 32Mbit Flash



6 Solder-Reflow Condition

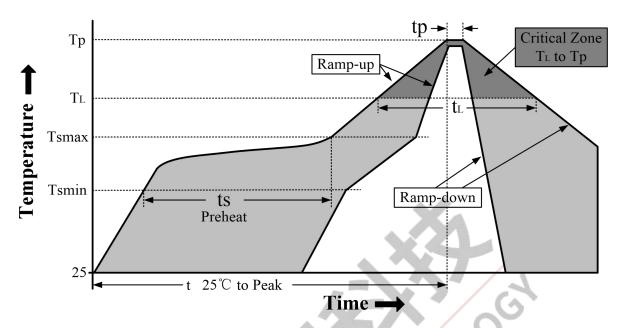


Figure 6-1 Classification Reflow Profile

Classification Profiles

Table 6-1

	Profile Feature	Sn-Pb Eutectic Assembly	Pb-Free Assembly
	Temperature Min (T _{smin})	100 °C	150 °C
Preheat/	Temperature Max (T _{smax})	150 °C	200 ℃
Soak	Time (ts) from (T _{smin} to T _{sma} x)	60-120 seconds	60-180 seconds
Average ra	amp-up rate $(T_{smax} \text{ to } T_p)$	3 °C/second max	3 °C/second max
Liquidous	temperature (T _L)	183 °C	217 ℃
Time (t _L) 1	maintained above T _L	60-150 seconds	60-150 seconds
Peak pack	age body temperature (Tp)	See Table 6-2.	See Table 6-3.
Time within 5°C of actual Peak Temperature (tp)		10-30 seconds	20-40 seconds
Ramp-down rate (T _p to T _L)		6 °C/second max.	6 °C/second max.
Time 25 °	C to peak temperature	6 minutes max.	8 minutes max.

Note 1: All temperatures refer to topside of the package, measured on the package body surface.

Note 2: Time within 5° C of actual peak temperature (tp) specified for the reflow profiles is a "supplier" minimum and "user" maximum.

SnPb - Classification Temperature

Table 6-2

Package	Volume mm ³	Volume mm ³
Thickness	< 350	≥ 350
<2.5 mm	240 +0/-5 ℃	225 +0/-5 °C
≥ 2.5 mm	225 +0/-5 °C	225 +0/-5 °C



Pb-free - Classification Temperature Table 6-3

Package Thickness	Volume mm³ < 350	Volume mm ³ 350 - 2000	Volume mm ³ > 2000
< 1.6mm	260 ℃	260 ℃	260 ℃
1.6 mm - 2.5mm	260 ℃	250 ℃	245 ℃
> 2.5mm	250 ℃	245 ℃	245 ℃





7 Revision History

Date	Revision	Description
2023.07.05	V1.0	Initial Release.
2023.09.28	V1.1	Update Pin Definition. Update Features modification.

